

PROCESSING

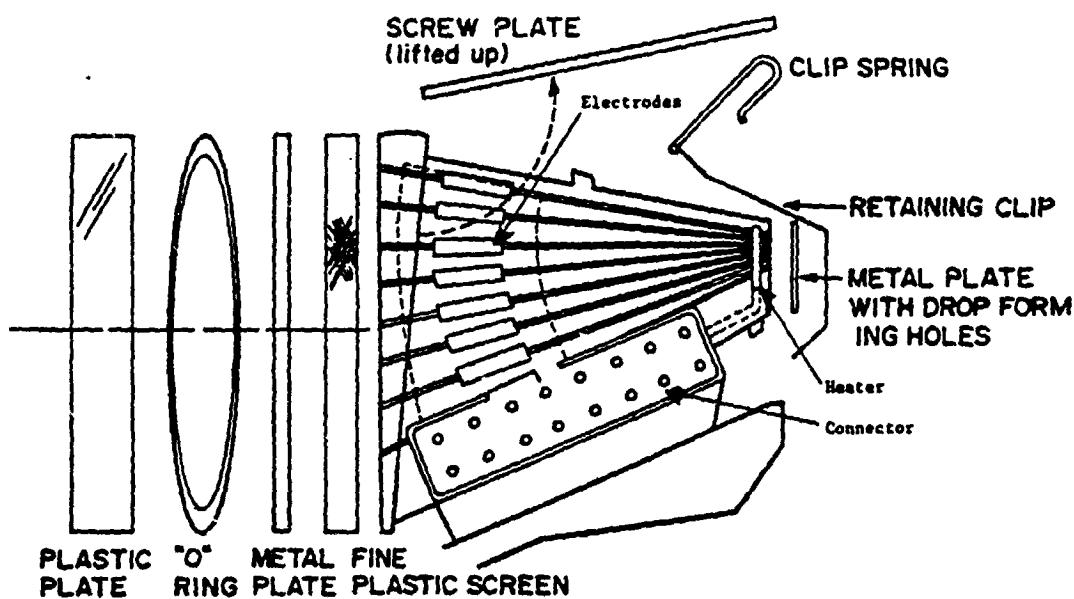
N87-16421

INK-JET PRINTING OF SILVER METALLIZATION  
FOR PHOTOVOLTAICS

PURDUE UNIVERSITY

R. W. Vest

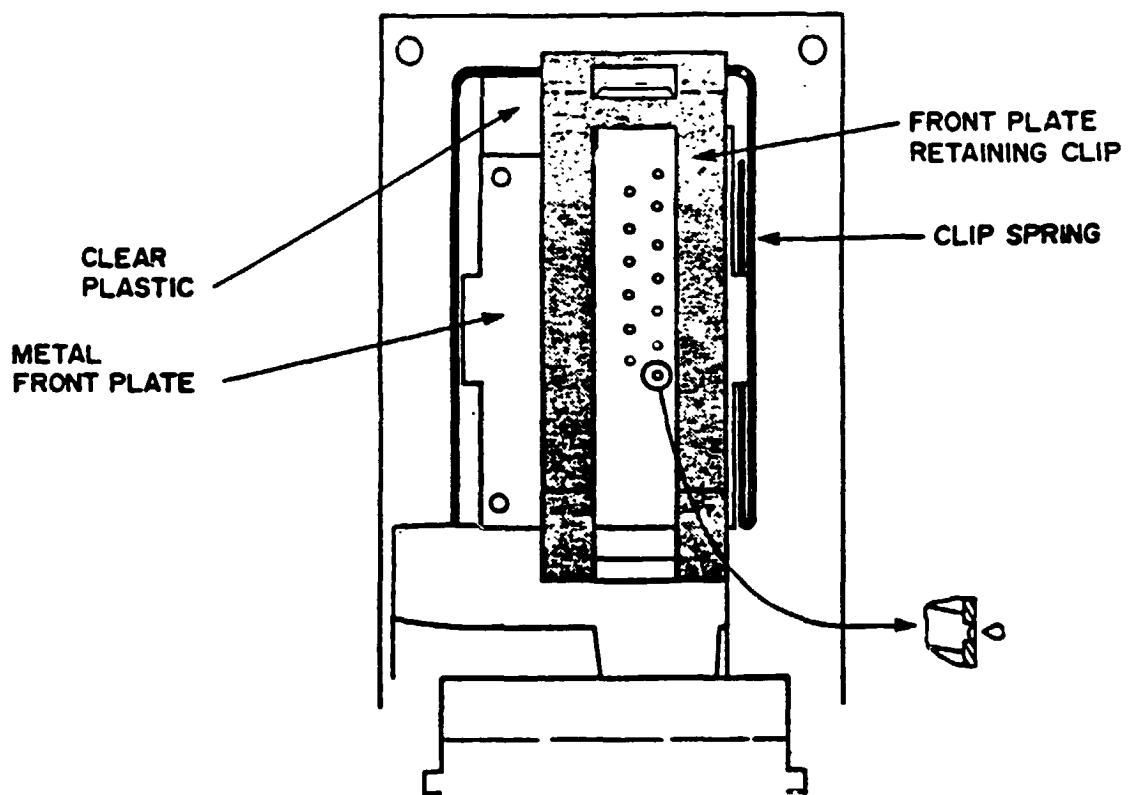
Nozzle Assembly (side view)



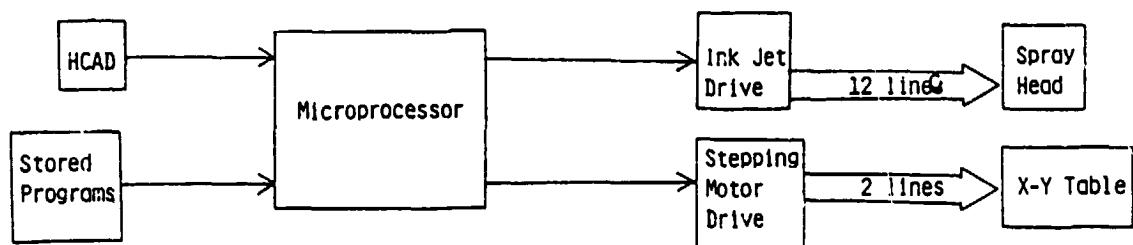
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## PROCESSING

### Nozzle Assembly (front view)



### Flow Diagram of Ink-Jet Printer System



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Computer Controlled Ink-Jet Printer

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Print Head and Substrate Mount



## PROCESSING

### Ink Requirements

1. No Particulates
2. Low Viscosity
3. High Surface Tension
4. High Inorganic Content
5. Non Clogging
6. Stable

### Ink Chemistry

1. Silver Compound  
Ag neodecanoate
2. Adhesion Agent  
Bi 2-ethylhexanoate
3. Solvent  
toluene or xylene
4. Stabilizer  
neodecanoic acid

## PROCESSING

### Ink-Jet Printing Studies

#### Ink Parameters

1. viscosity
2. surface tension
3. metal content
4. solvent vapor pressure

#### Printer Parameters

1. pulse voltage
2. pulse frequency
3. ink pressure
4. nozzle diameter
5. nozzle-substrate separation

#### Substrate Parameters

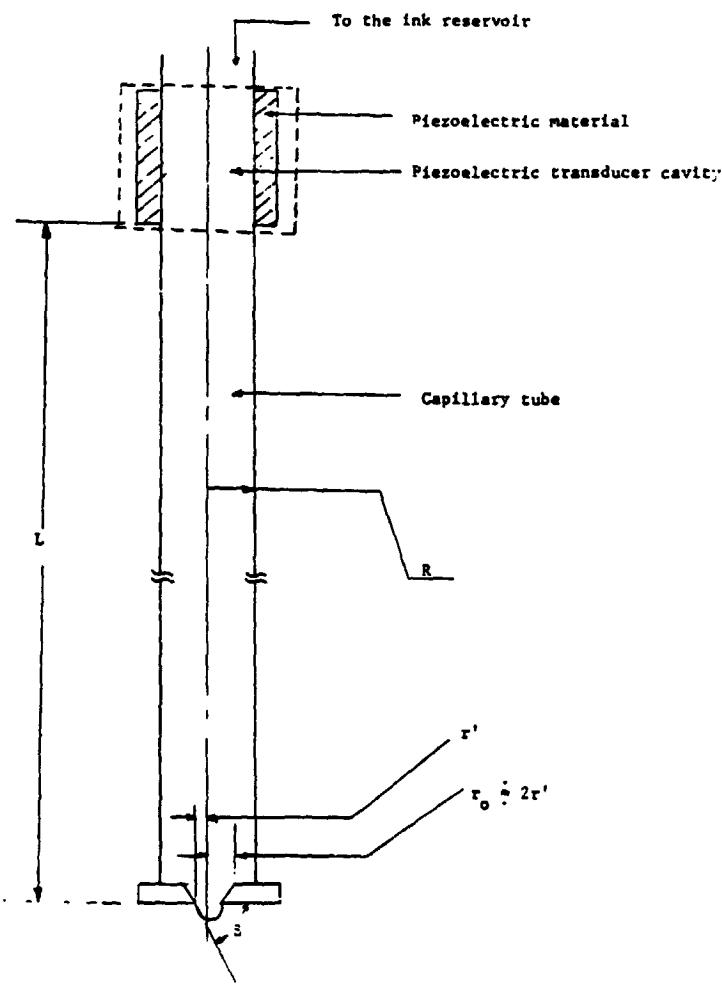
1. velocity
2. temperature

#### Firing Parameters

1. heating rate
2. maximum temperature
3. time at maximum temperature

## PROCESSING

Diagram of the Ink-Jet Model



## PROCESSING

### Ink-Jet Theory

$$Q_f = \pi T \frac{\sigma R^2 r_0^2 K}{8 \mu L} \left[ 1 - \frac{1}{2} \left( \frac{r_0}{R} \right)^2 \right] \left[ C V^n - \frac{2 \sigma \cos \theta}{r_f} \right]$$

#### Ink Parameters

- $\sigma$  = surface tension
- $\theta$  = contact angle
- $\mu$  = viscosity

#### Mechanical Parameters

- $r'$  = nozzle radius
- $r_0 = 2r'$

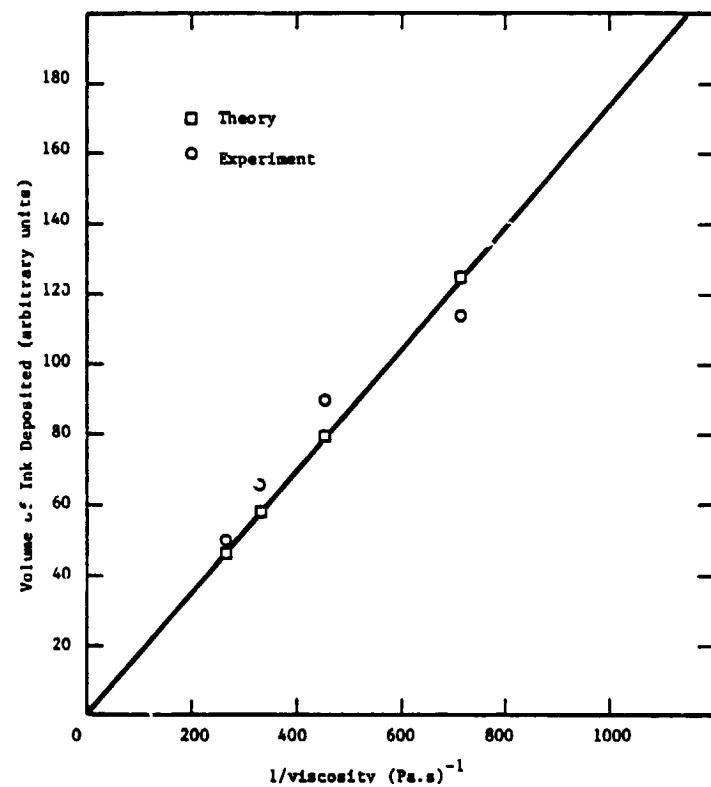
#### Electrical Parameters

- $V$  = pulse voltage
- $T$  = pulse duration
- $f$  = pulse frequency

R, K, L, C and n are constant for a given printer.

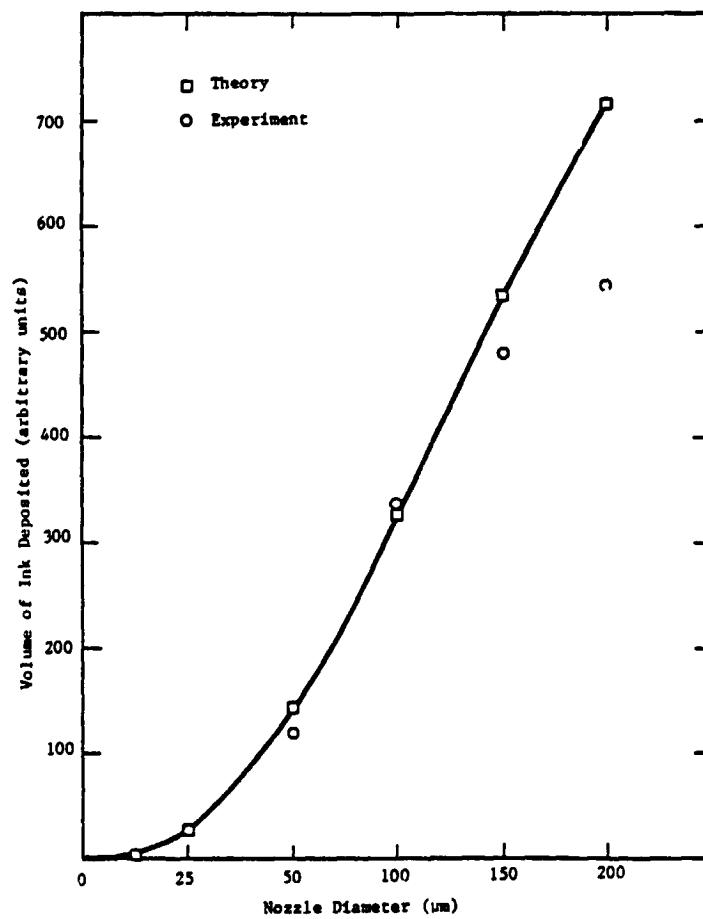
## PROCESSING

### Relationship of Ink-Flow Rate and Ink Viscosity



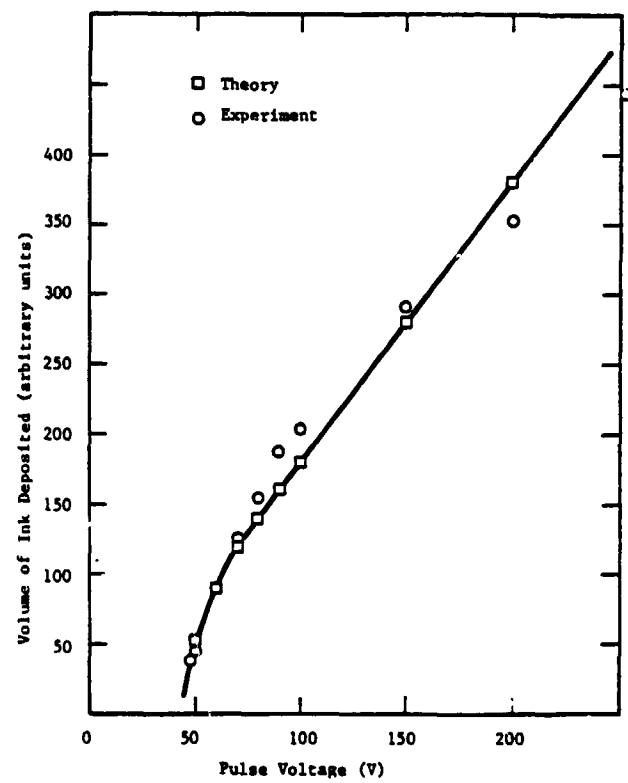
## PROCESSING

### Relationship of Ink-Flow Rate and Nozzle Diameter



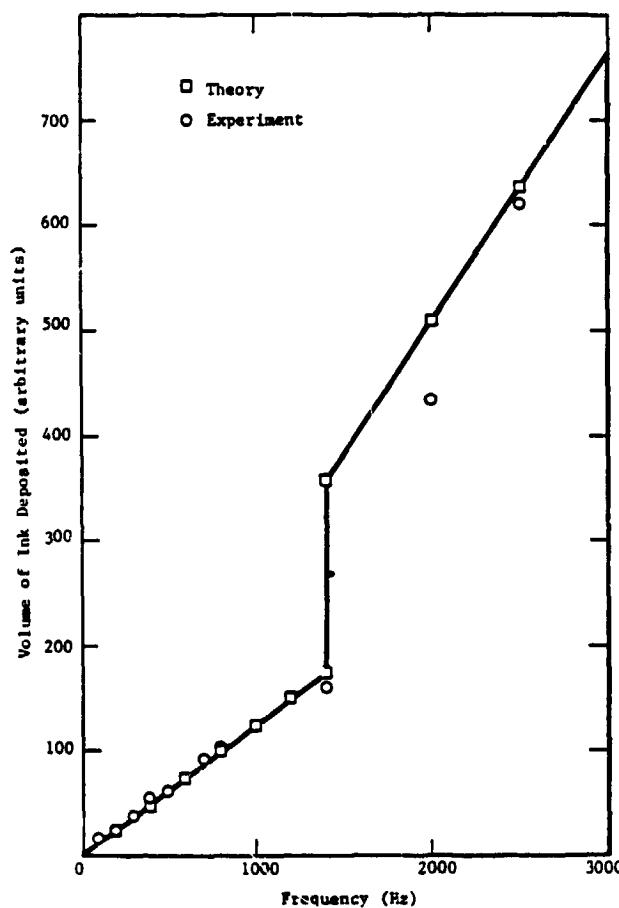
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Relationship of Ink-Flow Rate and Pulse Voltage Applied  
to the Piezoelectric Transducer



## PROCESSING

### Relationship of Ink-Flow Rate and Frequency of Pulses to the Piezoelectric Driver



### Thermal Processing

#### Belt Furnace

$T_{max} = 280^{\circ}$  to  $400^{\circ}\text{C}$

cycle time = 40 - 70 minutes

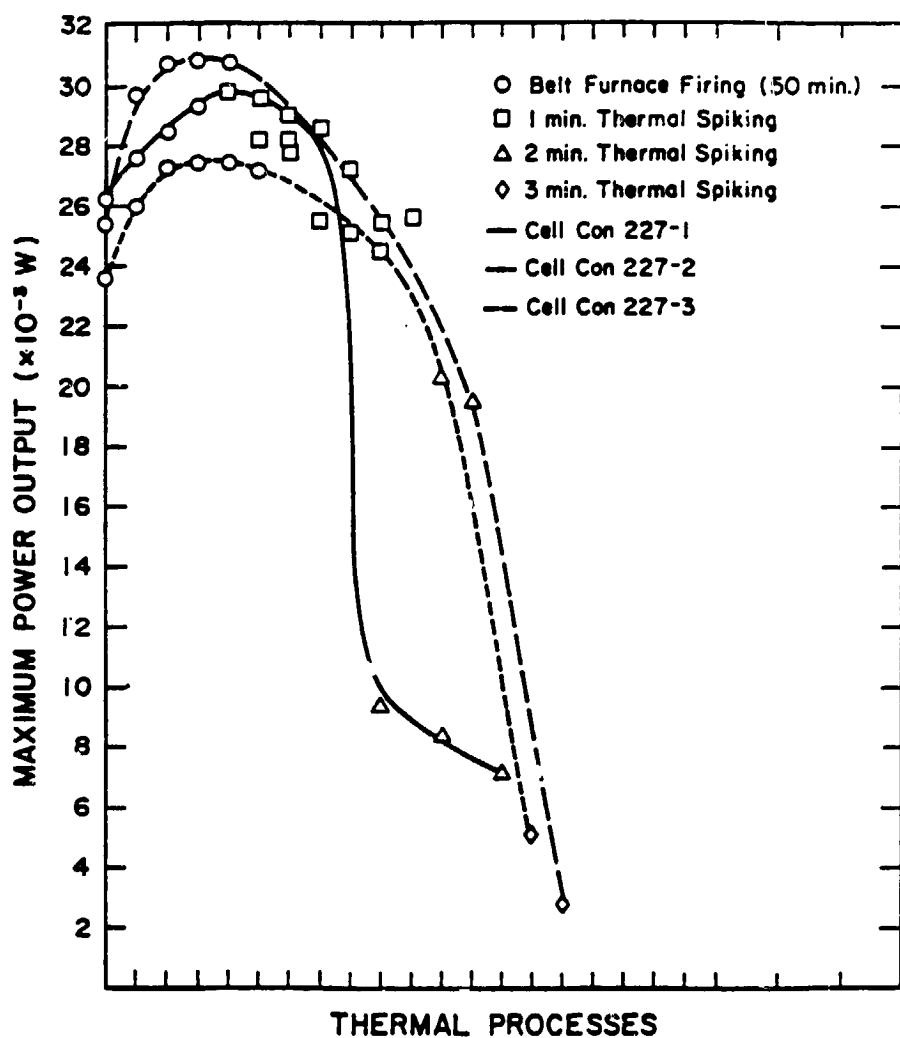
#### Thermal Spike

$750^{\circ}$  to  $850^{\circ}\text{C}$

45 to 180 seconds

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### Thermal Effects on Performance of Thin-Film (Control) Solar Cells



## PROCESSING

### Fired Film Properties

#### Composition

99% Ag - 1%  $\text{Bi}_2\text{O}_3$

#### Adhesion

excellent (Scotch tape)

#### Solderability

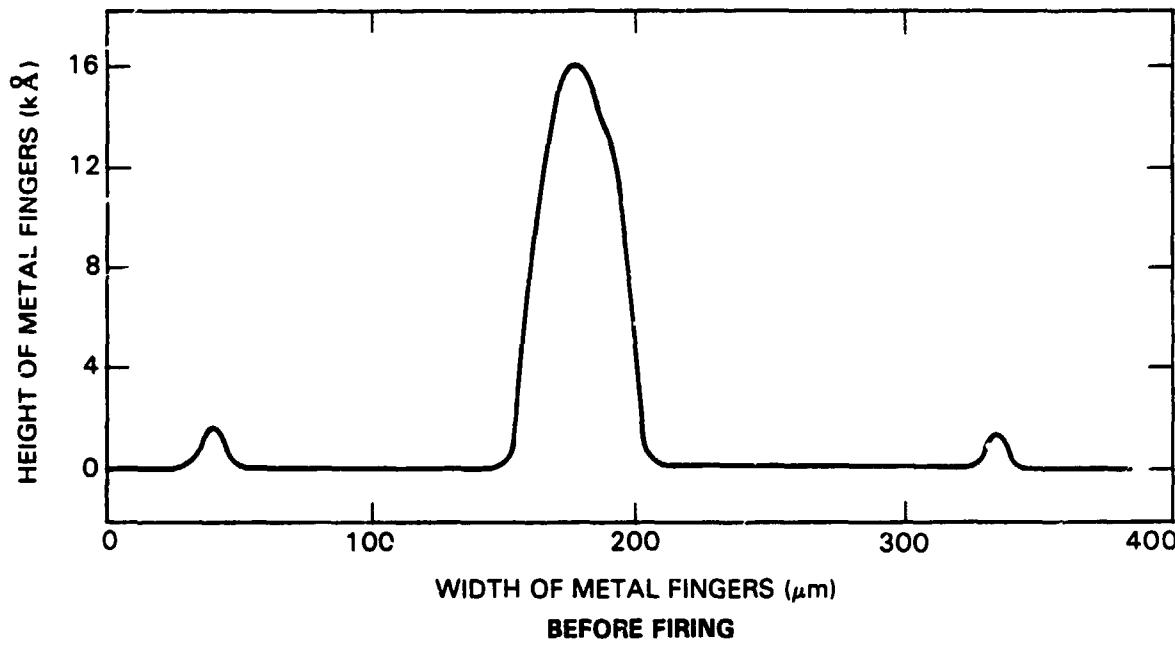
excellent (100% acceptance)

#### Solder Leach Resistance

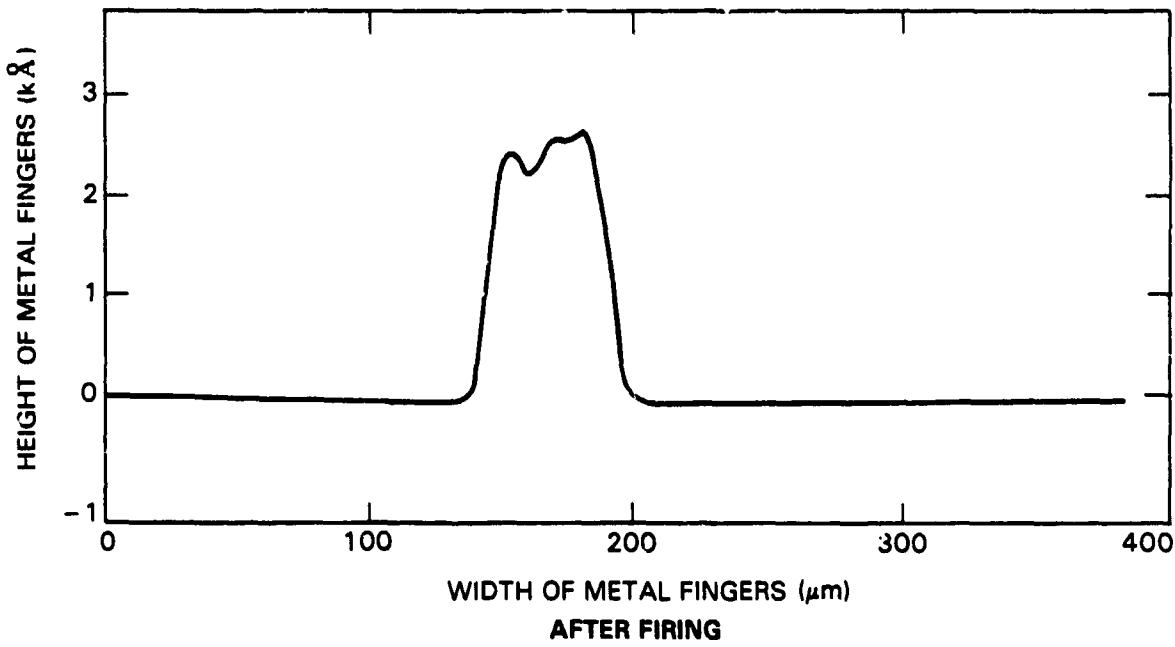
excellent (30 second dip)

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Height Versus Width of Metal Fingers



BEFORE FIRING



AFTER FIRING

PROCESSING

Measured Finger-to-Finger Resistances ( $R_{ff}$ ) and Series Resistance ( $R_{SE}$ )  
Calculated from I-V Curves for Solar Cells with Different Processing

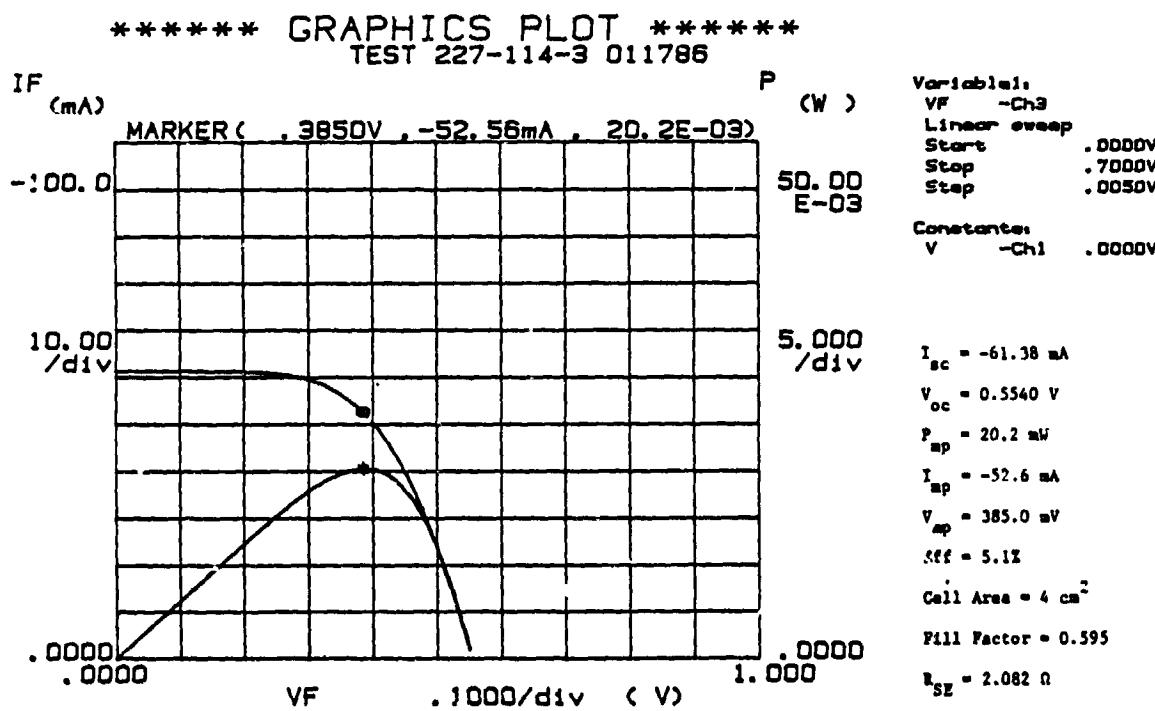
| No. of<br>Layers<br>of Ag | Thermal Treatment Sequence (a) |                     |                    |          |                             |                    |                                  |                     |   |                     | JPL<br>Control<br>Cells |   |
|---------------------------|--------------------------------|---------------------|--------------------|----------|-----------------------------|--------------------|----------------------------------|---------------------|---|---------------------|-------------------------|---|
|                           | (1)<br>B+60S                   |                     | (2)<br>B+60S+B     |          | (3)<br>B+60S+B <sup>2</sup> |                    | (4)<br>B+60S+B <sup>2</sup> +15S |                     | (5)<br>B+60S+B <sup>2</sup> +15S <sup>2</sup> |                     |                         |   |
|                           | $R_{ff}$                       | $R_{SE}$            | $R_{ff}$           | $R_{SE}$ | $R_{ff}$                    | $R_{SE}$           | $R_{ff}$                         | $R_{SE}$            | $R_{ff}$                                      | $R_{SE}$            | $R_{ff}$                | $R_{SE}$                                    |
| 5                         | 9.38<br>$\pm 1.22$             | 10.05<br>$\pm 1.79$ | 8.26<br>$\pm 0.13$ | -        | 8.13<br>$\pm 0.42$          | 9.48<br>$\pm 1.33$ | 8.76<br>$\pm 0.59$               | 10.92<br>$\pm 0.67$ | 8.57<br>$\pm 0.40$                            | 10.59<br>$\pm 1.57$ |                         |   |
| 10                        |                                |                     | 5.52<br>$\pm 0.35$ | -        | 5.13<br>$\pm 0.39$          | 7.98<br>$\pm 0.89$ | 3.43<br>$\pm 0.18$               | 7.16<br>$\pm 0.48$  | 3.41<br>$\pm 0.18$                            | 6.73<br>$\pm 0.43$  |                         |   |
| 20                        |                                |                     |                    |          |                             |                    | 2.44<br>$\pm 0.12$               | 4.35<br>$\pm 1.77$  | 1.65<br>$\pm 0.05$                            | 5.40<br>$\pm 0.71$  |                         |   |
|                           |                                |                     |                    |          |                             |                    |                                  |                     |   |                     | 5.22<br>$\pm 1.32$      | 1.49<br>$\pm 0.09$<br>0.63(b)<br>$\pm 0.12$ |

(a) thermal treatments

B = belt furnace with 70 minute cycle and 300°C maximum temperature  
60S = sixty seconds at 800°C  
15S = fifteen seconds at 800°C

(b) calculated from the I-V curves supplied by JPL

Current-Voltage Curve for 20-Layer Cell 114-3 After  
Thermal Treatment Step 4



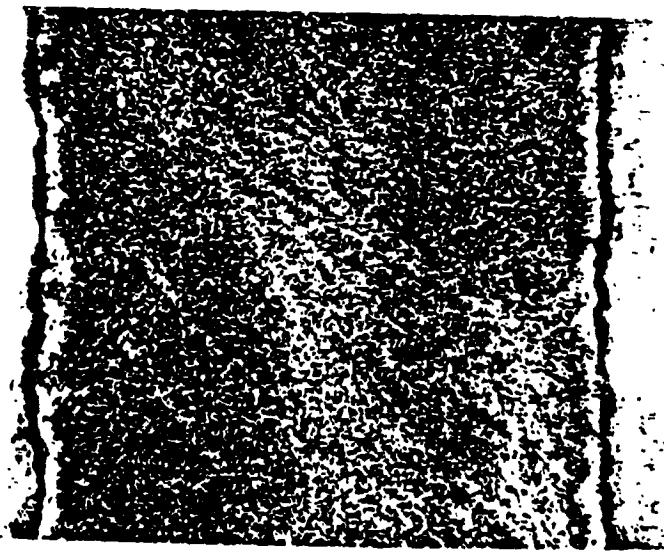
Current-Voltage Curve for 20 Layer Cell 114-3 After  
Thermal Treatment Step 4.

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Effect of Quality of the Metal Film on Solar Cell Quality



(a) Cell 227-15 Poor Metal Film and Poor Solar Cell



(b) Cell 227-14 Good Metal Film and Good Solar Cell

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## PROCESSING

### Comparison of Series Resistance ( $R_{SE}$ ) and Fill Factor (FF) for Solar Cells Metallized with MOD Silver With and Without a Ti/Pd Underlayer

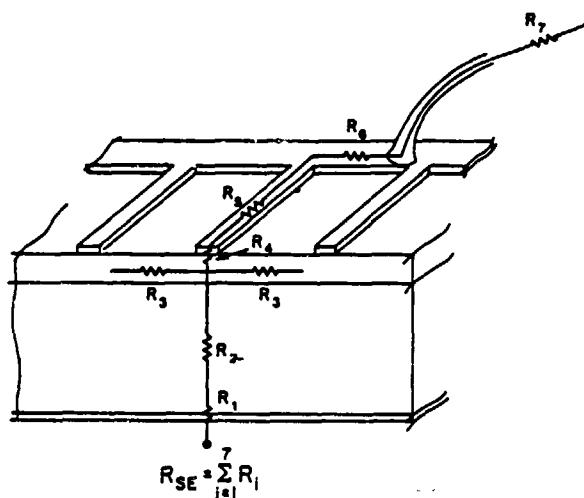
| No. of Layers of Ag | Thermal Treatment Sequence (a) |               |               |               |                 |               |               |               | JPL Control Cells |               |               |               |
|---------------------|--------------------------------|---------------|---------------|---------------|-----------------|---------------|---------------|---------------|-------------------|---------------|---------------|---------------|
|                     | B + 60S                        |               |               |               | B + 6JS + B     |               |               |               | Purdue Data       |               | JPL Data      |               |
|                     | No Ti/Pd                       | With Ti/Pd    | No Ti/Pd      | With Ti/Pd    | No Ti/Pd        | With Ti/Pd    | No Ti/Pd      | With Ti/Pd    | $R_{SE}$          | FF            | $R_{SE}$      | FF            |
| 5                   | 39.78<br>±10.09                | 0.22<br>±0.02 | 2.48<br>±0.79 | 0.51<br>±0.07 | 32.67<br>±15.15 | 0.24<br>±0.02 | 1.78<br>±0.25 | 0.57<br>±0.04 |                   |               |               |               |
| 10                  |                                |               |               |               | 20.04<br>±3.12  | 0.24<br>±0.01 | 1.75<br>±0.41 | 0.58<br>±0.03 | 1.70<br>±0.36     | 0.56<br>±0.04 | 0.69<br>±0.04 | 0.65<br>±0.03 |

(a) thermal treatments

B = belt furnace with 70 minute cycle and 300°C maximum temperature

60S = sixty seconds at 800°C

### Seven Factors that Contribute to the Measured Series Resistance of a Solar Cell



- |                        |                           |
|------------------------|---------------------------|
| $R_1$ = Back Contact   | $R_5$ = Grid Lines        |
| $R_2$ = Bulk           | $R_6$ = Bus Lines         |
| $R_3$ = Diffused Layer | $R_7$ = Measuring Circuit |
| $R_4$ = Front Contact  |                           |

## PROCESSING

### Summary

1. A computer controlled ink jet printing system was developed.
2. A theoretical model which adequately describes the ink jet printer was developed.
3. A MOD silver ink was developed for use with the printer.
4. Grid patterns with suitably low sheet resistance can be produced.
5. Line definition to 50  $\mu\text{m}$  can be achieved.
6. Good adhesion and solder leach resistance was demonstrated.
7. The contact resistance must be reduced in order to produce high efficiency cells.